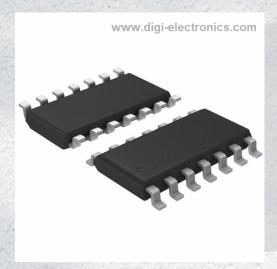


SN74HC11DR Datasheet



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DiGi Electronics Part Number

SN74HC11DR-DG

Manufacturer

Texas Instruments

Manufacturer Product Number

SN74HC11DR

Description

IC GATE AND 3CH 3-INP 14SOIC

Detailed Description

AND Gate IC 3 Channel 14-SOIC



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
SN74HC11DR	Texas Instruments
Series:	Product Status:
74HC	Active
Logic Type:	Number of Circuits:
AND Gate	3
Number of Inputs:	Features:
3	
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 6V	2 μΑ
Current - Output High, Low:	Input Logic Level - Low:
5.2mA, 5.2mA	0.5V ~ 1.8V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 4.2V	17ns @ 6V, 50pF
Operating Temperature:	Mounting Type:
-40°C ~ 85°C	Surface Mount
Supplier Device Package:	Package / Case:
14-SOIC	14-SOIC (0.154", 3.90mm Width)
Base Product Number:	
74HC11	

Environmental & Export classification

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



SN74HC11, SN54HC11

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SNx4HC11 Triple 3-Input AND Gates

1 Features

- **Buffered inputs**
- Wide operating voltage range: 2 V to 6 V
- Wide operating temperature range: -40°C to +85°C
- Supports fanout up to 10 LSTTL loads
- Significant power reduction compared to LSTTL logic ICs

2 Applications

- Combining power good signals
- Enable digital signals

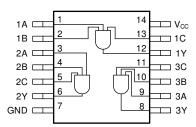
3 Description

This device contains three independent 3-input AND gates. Each gate performs the Boolean function $Y = A \bullet B \bullet C$ in positive logic.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)				
SN74HC11DR	SOIC (14)	8.70 mm × 3.90 mm				
SN74HC11NR	PDIP (14)	19.30 mm × 6.40 mm				
SN74HC11NSR	SO (14)	10.20 mm × 5.30 mm				
SN74HC11PWR	TSSOP (14)	5.00 mm × 4.40 mm				
SN54HC11JR	CDIP (14)	21.30 mm × 7.60 mm				
SN54HC11WR	CFP (14)	9.20 mm × 6.29 mm				
SN54HC11FKR	LCCC (20)	8.90 mm × 8.90 mm				

For all available packages, see the orderable addendum at the end of the data sheet.



Functional pinout



Table of Contents

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9	13 Mechanical, Packaging, and Orderable	
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	11234444456666699	 8.3 Feature Description. 8.4 Device Functional Modes. 9 Application and Implementation. 9.1 Application Information. 9.2 Typical Application. 10 Power Supply Recommendations. 11 Layout. 11.1 Layout Guidelines. 11.2 Layout Example. 12 Device and Documentation Support. 12.1 Documentation Support. 12.2 Related Links. 12.3 Support Resources. 12.4 Trademarks. 12.5 Electrostatic Discharge Caution. 12.6 Glossary. 13 Mechanical, Packaging, and Orderable

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision D (August 2003) to Revision E (April 2021)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Updated to new data sheet standards	1
•	increased thermals for D, PW and NS packages and decreased N package thermals	4

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5 Pin Configuration and Functions

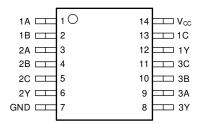


Figure 5-1. D, N, NS, PW, J, or W Package 14-Pin SOIC, PDIP, SO, TSSOP, CDIP, or CFP Top View

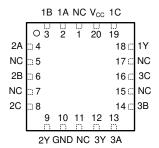


Figure 5-2. FK Package 20-Pin LCCC Top View

Pin Functions

PIN									
NAME	D, N, NS, PW, J, or W	FK	I/O	DESCRIPTION					
1A	1	2	Input	Channel 1, Input A					
1B	2	3	Input	Channel 1, Input B					
2A	3	4	Input	Channel 2, Input A					
2B	4	6	Input	Channel 2, Input B					
2C	5	8	Input	Channel 2, Input C					
2Y	6	9	Output	Channel 2, Output Y					
GND	7	10	_	Ground					
3Y	8	12	Output	Channel 3, Output Y					
3A	9	13	Input	Channel 3, Input A					
3B	10	14	Input	Channel 3, Input B					
3C	11	16	Input	Channel 3, Input C					
1Y	12	18	Output	Channel 1, Output Y					
1C	13	19	Input	Channel 1, Input C					
V _{CC}	14	20	_	Positive Supply					
NC		1, 5, 7, 11, 15, 17	_	Not internally connected					



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	V _I < 0 V or V _I > V _{CC}		±20	mA
I _{OK}	Output clamp current ⁽²⁾	$V_O < 0 \text{ V or } V_O > V_{CC}$		±20	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±25	mA
	Continuous current through V _{CC} or GND			±50	mA
TJ	Junction temperature ⁽³⁾		150	°C	
T _{stg}	Storage temperature		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) Guaranteed by design.

6.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage	,	2	5	6	V	
		V _{CC} = 2 V	1.5				
V_{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15			V	
		V _{CC} = 6 V	4.2	-			
		V _{CC} = 2 V		-	0.5		
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V			1.35	V	
		V _{CC} = 6 V			1.8		
VI	Input voltage		0		V _{CC}	V	
Vo	Output voltage		0	-	V _{CC}	V	
		V _{CC} = 2 V		-	1000		
Δt/Δν	Input transition rise and fall rate	V _{CC} = 4.5 V			500	ns	
		V _{CC} = 6 V			400		
т	Operating free air temperature	SN54HC00	-55		125	°C	
T_A	Operating free-air temperature	SN74HC00	-40		85	C	

6.3 Thermal Information

THERMAL METRIC(1)		D (SOIC)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	133.6	65.2	122.6	151.7	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	89.0	52.9	81.8	79.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	89.5	44.9	83.8	94.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	45.5	32.5	45.4	25.2	°C/W

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			SN74	HC11		
	THERMAL METRIC(1)	D (SOIC) N (PDIP)		NS (SOP)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	
Ψ_{JB}	Junction-to-board characterization parameter	89.1	44.7	83.4	94.1	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.4 Electrical Characteristics - 74

over operating free-air temperature range; typical values measured at $T_A = 25$ °C (unless otherwise noted).

			3 , ,1			perating							
P.	PARAMETER		TEST CONDITIONS			25°C		-40°	C to 85°	С	UNIT		
					MIN	TYP	MAX	MIN	TYP	MAX			
				2 V	1.9	1.998		1.9					
	l		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4					
V _{OH}	High-level output voltage	$V_I = V_{IH}$ or V_{IL}		6 V	5.9	5.999		5.9			V		
	- Carpar Fortage	5. T	I _{OH} = -4 mA	4.5 V	3.98	4.3		3.84					
			I _{OH} = -5.2 mA	6 V	5.48	5.8		5.34					
		vi V _I = V _{IH}			2 V		0.002	0.1			0.1		
			I _{OL} = 20 μA	4.5 V		0.001	0.1			0.1			
V _{OL}	Low-level output voltage					6 V		0.001	0.1			0.1	V
			I _{OL} = 4 mA	4.5 V		0.17	0.26			0.33			
			I _{OL} = 5.2 mA	6 V		0.15	0.26			0.33			
I _I	Input leakage current	V _I = V _{CC} o	or O	6 V			±0.1			±1	μΑ		
I _{CC}	Supply current	V _I = V _{CC} or 0	I _O = 0	6 V			2			20	μA		
C _i	Input capacitance			2 V to 6 V		3	10			10	pF		

6.5 Electrical Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

PARAMETER		AMETER TEST CONDITIONS			Operating free-air temperature (T _A)									
				V _{CC}		25°C		-40°	C to 85	°C	-55°C to 125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
				2 V	1.9	1.998		1.9			1.9			
			I _{OH} = -20 μΑ	4.5 V	4.4	4.499		4.4			4.4			
.,	High-level	High-level $V_I = V_{IH}$ or $V_{II} = V_{IH} = -4$	-	6 V	5.9	5.999		5.9			5.9			.,
V _{OH}	output voltage		4.5 V	3.98	4.3								V	
			I _{OH} = -5.2 mA	6 V	5.48	5.8								
				2 V		0.002	0.1			0.1			0.1	
			I _{OL} = 20 μΑ	4.5 V		0.001	0.1			0.1			0.1	
V _{OL}	Low-level output		-	6 V		0.001	0.1			0.1			0.1	V
	voltage	V _{IL}	$I_{OL} = 4 \text{ mA} 4.5^{\circ}$	4.5 V		0.17	0.26			0.33			0.4	
			I _{OL} = 5.2 mA	6 V		0.15	0.26			0.33			0.4	



over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

							Opera	ting free	-air tem	peratur	e (T _A)			
1	PARAMETER TEST CONDITIONS		NDITIONS	Vcc	25°C			-40°C to 85°C			-55°C to 125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
I	Current	V _I = V _{CC} or		6 V			±0.1			±1			±1	μА
I _{CC}	Supply current	V _I = V _{CC} or 0	I _O = 0	6 V			2			20			40	μА
Ci	Input capacitance			2 V to 6 V		3	10			10			10	pF

6.6 Switching Characteristics - 74

over operating free-air temperature range (unless otherwise noted)

					Operating free-air temperature (T _A)							
	PARAMETER		то	V _{CC}	25°C			-40°C to 85°C			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
				2 V		35	100			125		
t _{pd}	Propagation delay	A, B, or C	Y	4.5 V		10	20			25	ns	
				6 V		8	17			21		
				2 V		25	75			95		
t _t	Transition-time		Υ	4.5 V		7	15			19	ns	
				6 V		5	13			16		

6.7 Switching Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

	1 5 1					(Operati	ng free	air ten	nperatu	re (T _A)			
	PARAMETER		то	V _{cc}	C 25°C		-40°C to 85°C		5°C	-55°C to 125°C		5°C	UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
				2 V		35	100			125			150	
t _{pd}	Propagation delay	A, B, or C	or Y	4.5 V		10	20			25			30	ns
				6 V		8	17			21			25	
				2 V		25	75			95			110	
t _t	Transition-time		Y	4.5 V		7	15			19			22	ns
				6 V		5	13			16			19	

6.8 Operating Characteristics

over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
Cnd	Power dissipation capacitance per gate	No load	2 V to 6 V		25		pF

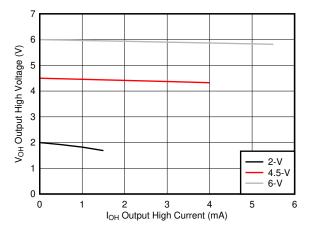
6.9 Typical Characteristics

 $T_A = 25^{\circ}C$

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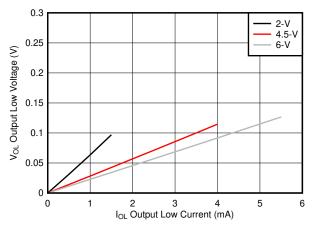


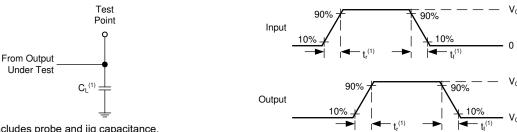
Figure 6-1. Typical output voltage in the high state (V_{OH})

Figure 6-2. Typical output voltage in the low state (V_{OL})



7 Parameter Measurement Information

- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_t < 6$ ns.
- The outputs are measured one at a time, with one input transition per measurement.

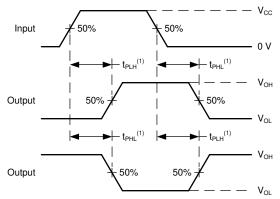


A. t_t is the greater of t_r and t_f.

A. C_L = 50 pF and includes probe and jig capacitance.

Figure 7-1. Load Circuit

Figure 7-2. Voltage Waveforms Transition Times



A. The maximum between t_{PLH} and t_{PHL} is used for t_{pd} .

Figure 7-3. Voltage Waveforms Propagation Delays

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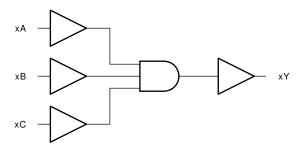
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8 Detailed Description

8.1 Overview

This device contains three independent 3-input AND gates. Each gate performs the Boolean function Y = A ● B ● C in positive logic.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to over-current. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

The SN74HC11 can drive a load with a total capacitance less than or equal to the maximum load listed in the *Switching Characteristics* - 74 connected to a high-impedance CMOS input while still meeting all of the datasheet specifications. Larger capacitive loads can be applied, however it is not recommended to exceed the provided load value. If larger capacitive loads are required, it is recommended to add a series resistor between the output and the capacitor to limit output current to the values given in the *Absolute Maximum Ratings*.

8.3.2 Standard CMOS Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor from the input to ground in parallel with the input capacitance given in the *Electrical Characteristics - 74*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics - 74*, using ohm's law $(R = V \div I)$.

Signals applied to the inputs need to have fast edge rates, as defined by the input transition time in the *Recommended Operating Conditions* to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal prior to the standard CMOS input.

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8.3.3 Clamp Diode Structure

The inputs and outputs to this device have both positive and negative clamping diodes as depicted in Figure 8-1.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The recommended input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

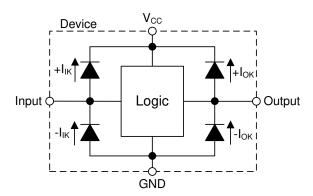


Figure 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

8.4 Device Functional Modes

Table 8-1. Function Table

	INPUTS		OUTPUT
Α	В	С	Y
Н	Н	Н	Н
L	Х	Х	L
Х	L	Х	L
Х	Х	L	L

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9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

In this application, this device is used to directly control the RESET pin of a motor controller. The controller requires three input signals to all be HIGH before being enabled, and should be disabled in the event that any one signal goes LOW. The 3-input AND gate function combines the three individual reset signals into a single active-low reset signal.

9.2 Typical Application

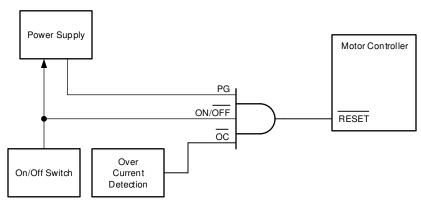


Figure 9-1. Typical application schematic

9.2.1 Design Requirements

9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics - 74*.

The supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74HC11 plus the maximum supply current, I_{CC} , listed in the *Electrical Characteristics - 74*. The logic device can only source or sink as much current as it is provided at the supply and ground pins, respectively. Be sure not to exceed the maximum total current through GND or V_{CC} listed in the *Absolute Maximum Ratings*.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and C_{pd} Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

CAUTION

The maximum junction temperature, $T_J(max)$ listed in the *Absolute Maximum Ratings*, is an *additional limitation* to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

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9.2.1.2 Input Considerations

Unused inputs must be terminated to either V_{CC} or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74HC11, as specified in the *Electrical Characteristics - 74*, and the desired input transition rate. A 10-k Ω resistor value is often used due to these factors.

The SN74HC11 has standard CMOS inputs, so input signal edge rates cannot be slow. Slow input edge rates can cause oscillations and damaging shoot-through current. The recommended rates are defined in the *Recommended Operating Conditions*.

Refer to Section 8.3 for additional information regarding the inputs for this device.

9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics - 74*. Similarly, the ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics - 74*.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to Section 8.3 for additional information regarding the outputs for this device.

9.2.2 Detailed Design Procedure

- 1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in Section 11.
- 2. Ensure the capacitive load at the output is ≤ 70 pF. This is not a hard limit, however it will ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74HC11 to the receiving device.
- 3. Ensure the resistive load at the output is larger than $(V_{CC} / I_O(max)) \Omega$. This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in megaohms; much larger than the minimum calculated above.
- 4. Thermal issues are rarely a concern for logic gates, however the power consumption and thermal increase can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation

9.2.3 Application Curves

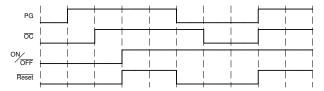


Figure 9-2. Typical application timing diagram



10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in *Figure 11-1*.

11 Layout

11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

11.2 Layout Example

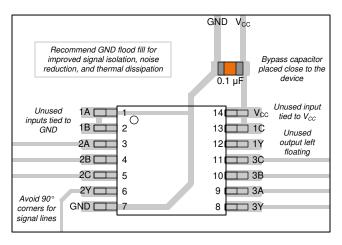


Figure 11-1. Example layout for the SN74HC11



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- HCMOS Design Considerations
- CMOS Power Consumption and CPD Calculation
- · Designing with Logic

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8404801VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8404801VC A SNV54HC11J	Samples
84048012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84048012A SNJ54HC 11FK	Samples
8404801CA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8404801CA SNJ54HC11J	Samples
8404801DA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8404801DA SNJ54HC11W	Samples
JM38510/65204BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65204BCA	Samples
M38510/65204BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65204BCA	Samples
SN54HC11J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC11J	Samples
SN74HC11D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	HC11	
SN74HC11DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC11	Samples
SN74HC11DT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	HC11	
SN74HC11N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC11N	Samples
SN74HC11NSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC11	Samples
SN74HC11PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85	HC11	
SN74HC11PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC11	Samples
SNJ54HC11FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84048012A SNJ54HC 11FK	Samples
SNJ54HC11J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8404801CA SNJ54HC11J	Samples
SNJ54HC11W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8404801DA SNJ54HC11W	Samples

SN74HC11DR Texas Instruments IC GATE AND 3CH 3-INP 14SOIC



PACKAGE OPTION ADDENDUM

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(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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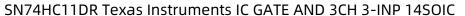
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54HC11, SN54HC11-SP, SN74HC11:

Catalog: SN74HC11, SN54HC11

Military: SN54HC11

Space: SN54HC11-SP





PACKAGE OPTION ADDENDUM

www.ti.com 2-Dec-2024

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC11DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC11NSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC11PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

_								
	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	SN74HC11DR	SOIC	D	14	2500	356.0	356.0	35.0
	SN74HC11NSR	SOP	NS	14	2000	356.0	356.0	35.0
	SN74HC11PWR	TSSOP	PW	14	2000	356.0	356.0	35.0



PACKAGE MATERIALS INFORMATION

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TUBE



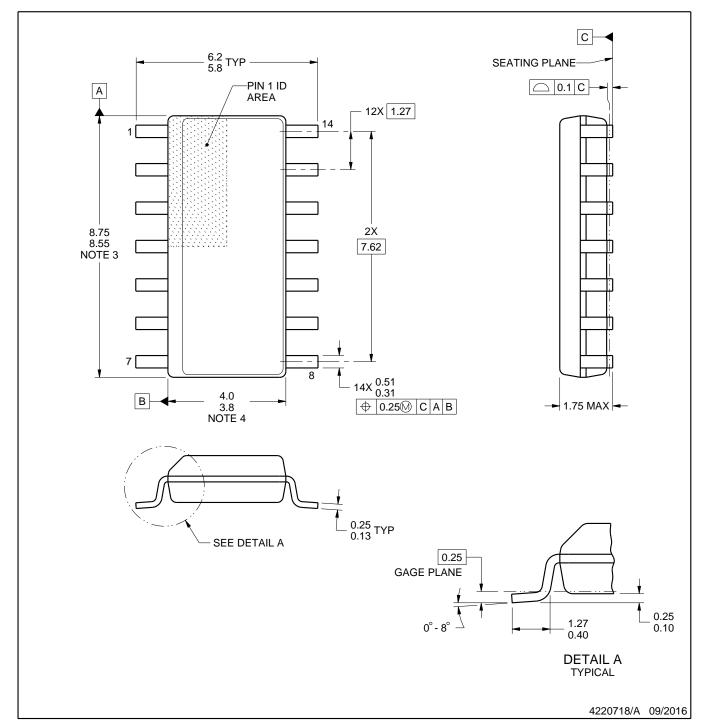
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
84048012A	FK	LCCC	20	55	506.98	12.06	2030	NA
8404801DA	W	CFP	14	25	506.98	26.16	6220	NA
SN74HC11N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC11N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54HC11FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC11W	W	CFP	14	25	506.98	26.16	6220	NA

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

D0014A

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

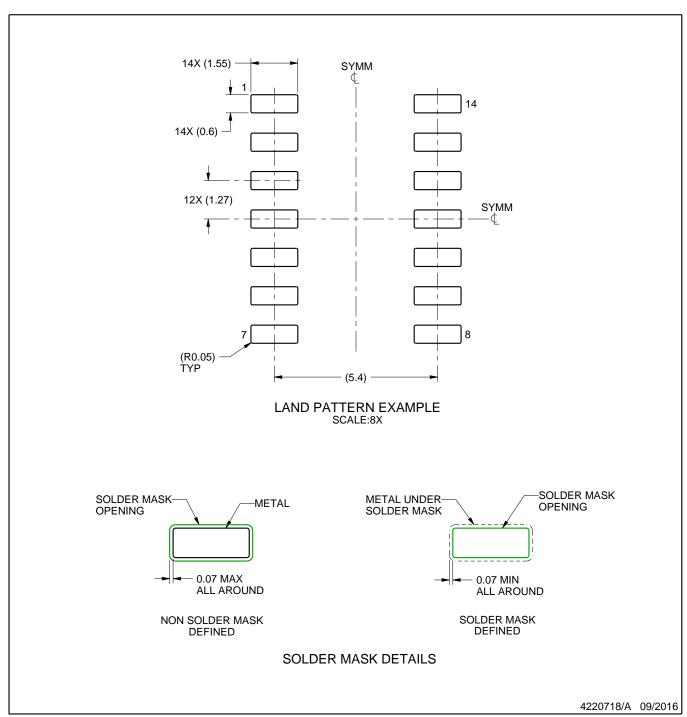
 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

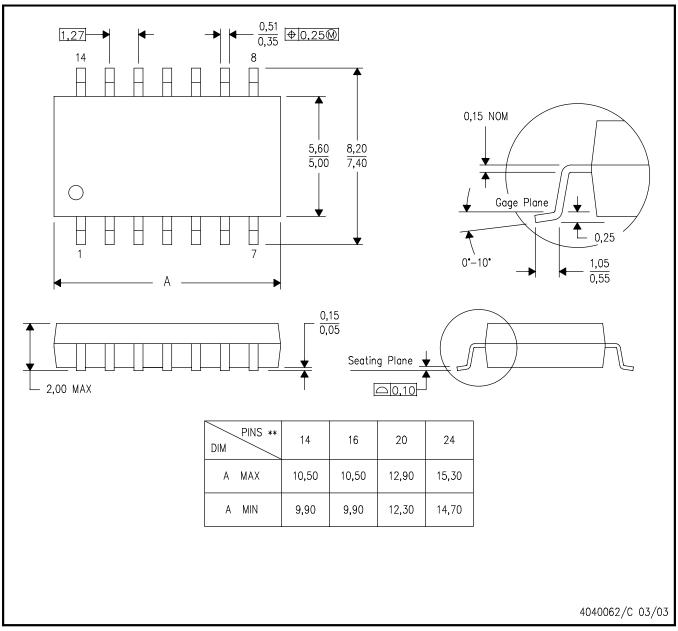


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

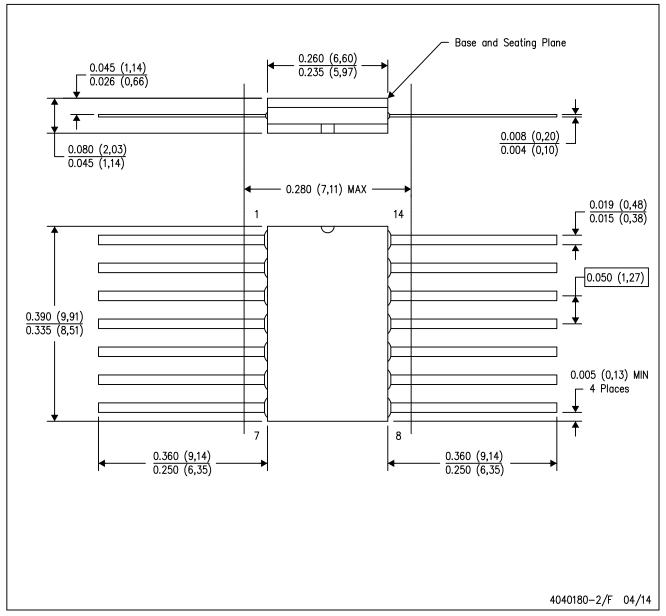
- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



GENERIC PACKAGE VIEW

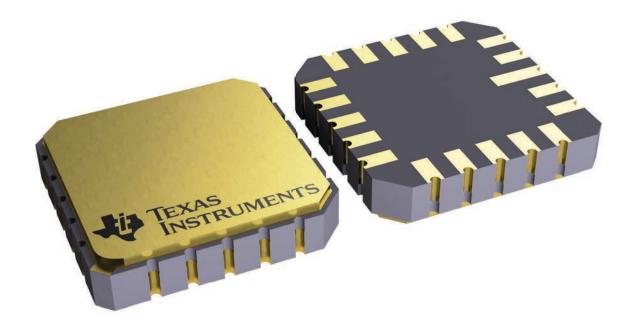
FK 20

LCCC - 2.03 mm max height

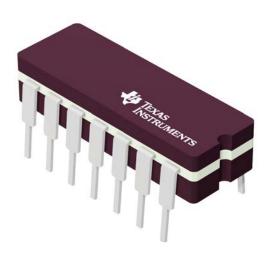
8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CDIP - 5.08 mm max height CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G

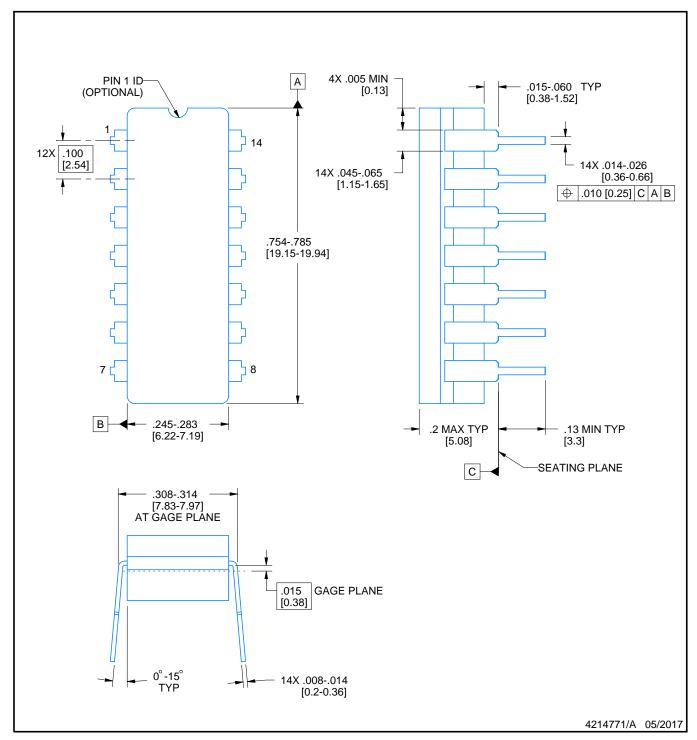




PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

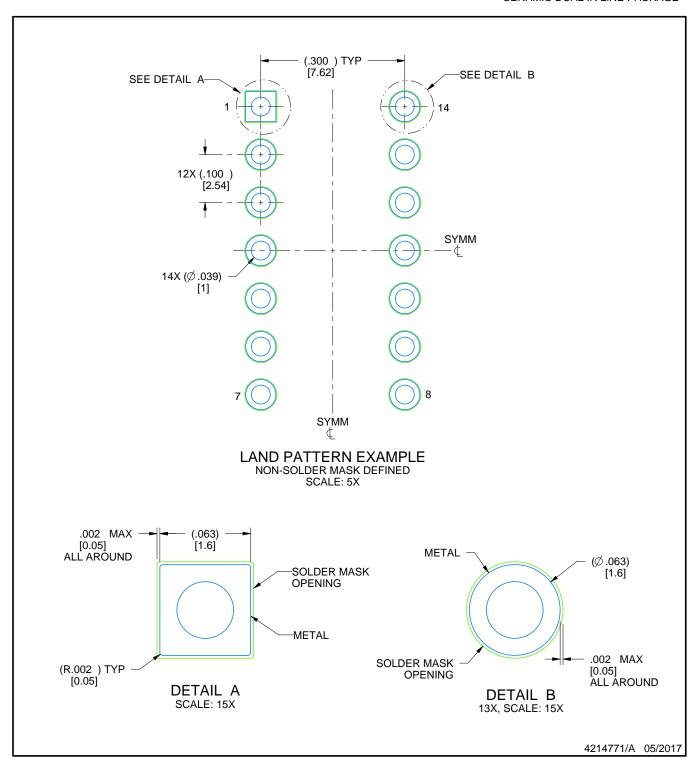
J0014A

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE

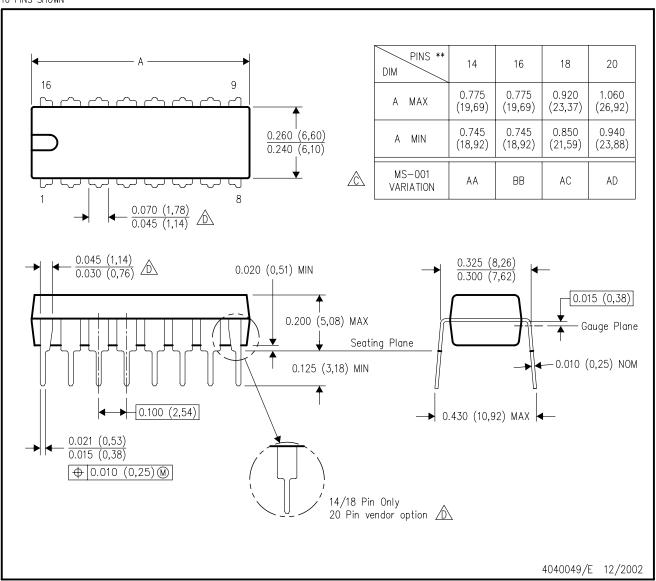


MECHANICAL DATA

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

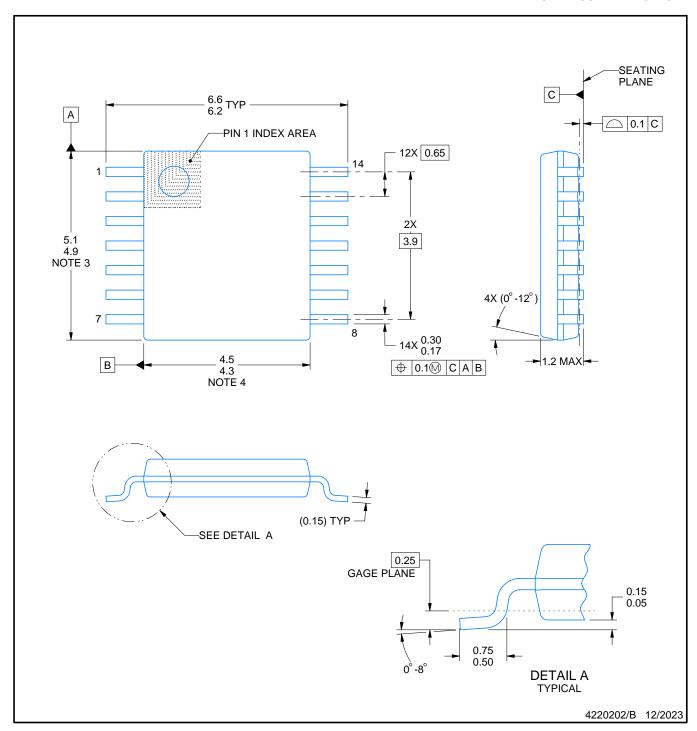
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



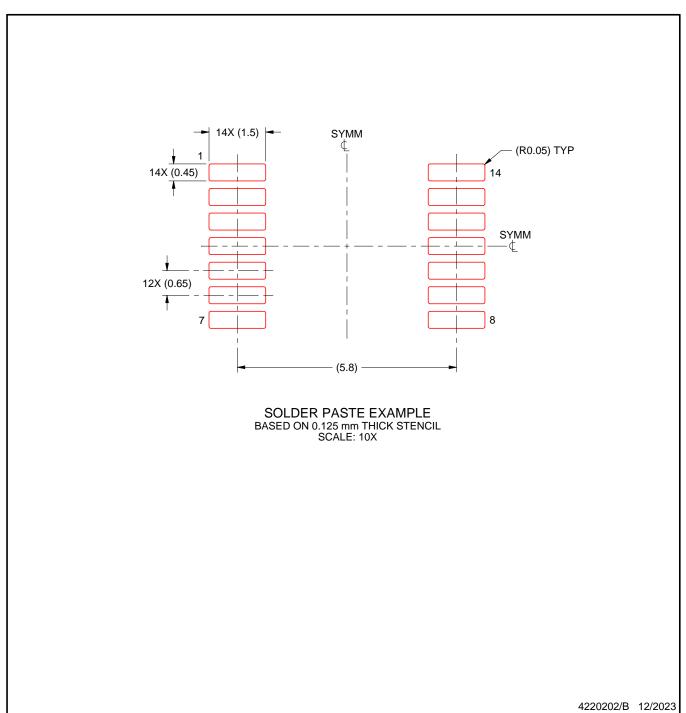
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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